



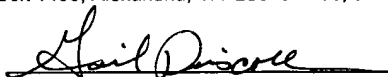
Docket No.: S1022.81021US00  
(PATENT)

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Applicant: Daniel Bensahel  
Serial No.: 10/614675  
Confirmation No.: 7318  
Filed: July 7, 2003  
For: GROWTH OF A SINGLE-CRYSTAL REGION OF A III-V COMPOUND  
ON A SINGLE-CRYSTAL SILICON SUBSTRATE  
Examiner: Felisa Carla Hiteshew  
Art Unit: 1722

I hereby certify that this correspondence is being deposited with the U.S. Postal Service with sufficient postage as First Class Mail, in an envelope addressed to: MS Amendment, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on the date shown below.

Dated: 8-26-05

  
Gail Driscoll

**AMENDMENT IN RESPONSE TO NON-FINAL OFFICE ACTION**

Mail Stop Amendment  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Dear Sir:

**INTRODUCTORY COMMENTS**

In response to the Office Action dated April 28, 2005, please amend the above-identified U.S. patent application as follows:

**Amendments to the Claims** are reflected in the listing of claims which begins on page 2 of this paper.

**Remarks/Arguments** begin on page 5 of this paper.